NSN 5961-01-332-8092

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-332-8092 **Inclosure Material:** Metal **Overall Length:** 1.453 inches **Function For Which Designed:** Rectifier **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case and electrostatic sensitive **Overall Width Across Flats:** Between 0.677 inches and 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 108.0 repetitive peak reverse voltage and 90.0 reverse voltage, instantaneous and 90.0 working peak reverse voltage **Current Rating Per Characteristic:** 70.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No